

Short communication

A novel low firing microwave dielectric ceramic $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$

Liang Fang*, Fei Xiang, Congxue Su, Hui Zhang

State Key Laboratory Breeding Base of Nonferrous Metals and Specific Materials Processing, Key laboratory of Nonferrous Materials and New Processing Technology, Ministry of Education, College of Material Science and Engineering, Guilin University of Technology, Guilin 541004, China

Received 5 May 2013; received in revised form 11 May 2013; accepted 11 May 2013

Available online 17 May 2013

Abstract

A novel low-firing microwave dielectric ceramic $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ was prepared by the conventional solid state ceramic route. The phase composition, microstructure, and sintering behavior were investigated. The $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ ceramic could be well densified at around 915 °C and exhibited favorable microwave dielectric properties with a low relative permittivity of ~ 10 , a high quality factor ($Q \times f$) of $\sim 50,600$ GHz, and a negative temperature coefficient of resonant frequency (τ_f) of -47 ppm/°C. The $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ ceramic can be compatible with Ag electrode, which makes it a promising ceramic for LTCC technology application. CaTiO_3 was added into the $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ ceramic to obtain a near zero τ_f , and $0.8\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}-0.2\text{CaTiO}_3$ ceramic sintered at 930 °C for 4 h showed improved properties with $\epsilon_r=11.5$, $Q \times f=37,500$ GHz, and $\tau_f=2$ ppm/°C.

© 2013 Elsevier Ltd and Techna Group S.r.l. All rights reserved.

Keywords: A. Sintering; C. Dielectric properties; E. Functional applications; Garnet

1. Introduction

Low-temperature co-fired ceramics (LTCC) has been generating considerable interest due to the benefits offered for the fabrication of miniature multilayer devices [1–4]. A typical LTCC module is a multilayered compact of ceramic substrates and common internal electrode material Ag which will melt at 961 °C. Advanced substrate materials for microwave integrated circuits should possess a high quality factor ($Q \times f$), a small temperature coefficient of resonant frequency (τ_f), and especially a low relative permittivity ($\epsilon_r < 15$) to avoid signal delay [5].

Several ceramics such as Al_2O_3 [6], Mg_2SiO_4 [7], $\text{Mg}_4\text{Nb}_2\text{O}_9$ [8], and MgSiO_3 [9] have been developed and regarded as low ϵ_r microwave dielectric ceramics. However, these ceramics suffer the disadvantage of high sintering temperatures. In order to reduce the sintering temperature of dielectric ceramics, adding sintering aids, such as low-melting glass or oxides, is the common method. But the microwave dielectric properties of the materials will be degraded seriously

as the glass or oxides will produce a large amount of amorphous phase in the materials.

Recently, some potential candidates for LTCC substrates have been concentrated on the compounds containing low melting point oxides [10–15]. Among these compounds, $\text{Mg}_2\text{V}_2\text{O}_7$ and $\text{R}_2\text{V}_2\text{O}_7$ ($\text{R}=\text{Ba}$, Sr , and Ca) ceramics possessed a good combination of microwave dielectric characteristics: $\epsilon_r=10\sim 12.1$, $Q \times f=15,200\sim 58,300$ GHz, and $\tau_f=-26\sim 35$ ppm/°C [14,15]. However, no investigations on their chemical compatibility with silver has been reported to date. Recently, we reported a low ϵ_r and high $Q \times f$ microwave dielectric ceramic $\text{LiCa}_3\text{MgV}_3\text{O}_{12}$ with cubic garnet-structure, which could be well sintered at 900 °C and was compatible with Ag electrode [16]. In $\text{Na}_2\text{O}-\text{CaO}-\text{MgO}-\text{V}_2\text{O}_5$ system, $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ also adopts the cubic garnet structure reported by Bayer and was synthesized at 750 °C [17]. Therefore, the $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ ceramic might have a low sintering temperature as well as good microwave dielectric properties to meet the requirement for LTCC application. In the present paper, the preparation and microwave dielectric properties of $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ ceramic were reported for the first time, and its chemical compatibility with silver electrode was also investigated to check whether the $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ ceramic is suitable for the LTCC

*Corresponding author. Tel./fax: +86 77 3589 6290.

E-mail address: fanglianggl001@yahoo.cn (L. Fang).

technology. Adjusting the temperature coefficients of resonant frequency (τ_f) of $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ ceramic by the addition of CaTiO_3 with a large positive τ_f value ($\sim +800$ ppm/ $^\circ\text{C}$) [18] was also studied.

2. Experimental procedure

$\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ ceramics were prepared using the solid-state ceramic route from high-purity powder of Na_2CO_3 , CaCO_3 , MgO , and V_2O_5 ($> 99\%$, Guo-Yao Co. Ltd., Shanghai, China). Since MgO is hygroscopic, it was calcined at 800°C for 2 h to remove moisture retains. Powders were mixed and milled for 4 h using a planetary mill (Nanjing Machine Factory, Nanjing, China) operating at a running speed of 150 rpm with ZrO_2 media using alcohol as a medium. The mixtures were dried and calcined at 800°C for 4 h. The calcined powder was re-milled for 6 h using 5 wt% of polyvinyl alcohol solution as a binder. The obtained powder was then crushed into a fine powder through a sieve with a 200 mesh. The obtained fine powder was then pressed into pellets of 12 mm in diameter and 7 mm in height by uniaxial pressing under a pressure of 200 MPa. The pellets were heated at 600°C for 4 h to remove the PVA and then sintered on a Pt foil at 885 – 945°C for 4 h.

The phase composition of the samples was analyzed by an X-ray diffraction measurement ($\text{CuK}\alpha_1$, 1.54059 \AA , Model X'Pert PRO, PANalytical, Almelo, Holland) with $\text{CuK}\alpha$ radiation generated at 40 kV and 100 mA. The bulk densities of sintered ceramics were measured by Archimedes' method. The surface microstructure of the samples was examined using a field emission scanning electron microscope (FE-SEM, Model S4800, Hitachi, Japan). Composition analysis was performed using energy-dispersive spectroscopy (EDS, IE 350; INCA, Oxford, U.K.). The microwave dielectric properties were analyzed using a network analyzer (Model N5230A, Agilent Co., Palo Alto, Canada) and a temperature chamber (Delta 9039, Delta Design, San Diego, CA). The temperature coefficient of resonant frequency τ_f values were calculated using the following formula:

$$\tau_f = \frac{f_{85} - f_{25}}{60f_{25}} \quad (1)$$

where f_{85} and f_{25} are the resonant frequencies at 85°C and 25°C , respectively.

3. Results and discussion

The X-ray diffraction pattern of the $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ (NCMV) ceramic sintered at 915°C for 4 h is shown in Fig. 1, and it can be fully indexed as single-phase with cubic garnet structure, which agreed well with the result reported by Bayer [17]. The FE-SEM micrograph of the surface of NCMV ceramic is also shown in Fig. 1. Homogenous microstructure with grains size in the range 1 – $5 \mu\text{m}$ and few pores could be observed for NCMV ceramic sintered at 915°C for 4 h.

The variations of relative density, ϵ_r , $Q_u \times f$, and τ_f of $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ ceramics as a function of the sintering

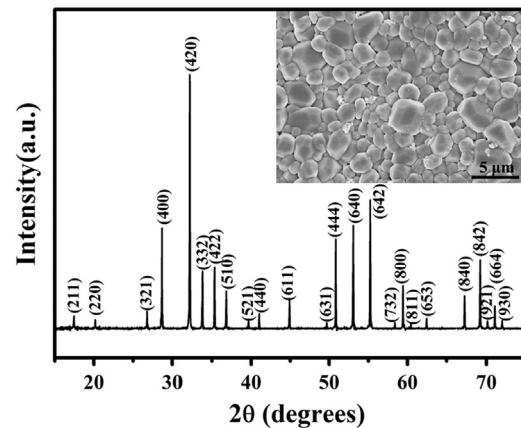


Fig. 1. X-ray diffraction result and FE-SEM image for the surface of a $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ ceramic sintered at 915°C for 4 h.

temperature were presented in Fig. 2. The relative density of $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ ceramic increased with increasing sintering temperature, reached a maximum value (95.8%) at 915°C , and then decreased slightly. Microwave dielectric properties versus sintering temperature of NCMV ceramics exhibited a trend similar to that of the relative density. ϵ_r increases from 8.8 to 10 as sintering temperature increases from 885 to 915°C . Then ϵ_r reaches saturation and maintains stability, which indicates that the ϵ_r of ceramic is associated with the elimination of the pores [10,19]. The influence of the porosity on the microwave permittivity could be eliminated by applying Bosman and Havinga's correction [20] as shown in Eq. (2).

$$\epsilon_{corrected} = \epsilon_m(1 + 1.5p) \quad (2)$$

where $\epsilon_{corrected}$ and ϵ_m are corrected and measured values of permittivity, respectively. p is the fractional porosity (0.042 in this work). The porosity corrected permittivity is about 10.75. The $Q_u \times f$ value of NCMV ceramics reaches the maximum with a value of 50,600 GHz. Thereafter, the $Q_u \times f$ values decrease with further increasing temperature, which may be due to the decreased densification caused by the evaporation of Na_2O [21]. τ_f values of NCMV ceramic do not change remarkably with increasing sintering temperature and remain stable at about -47 ppm/ $^\circ\text{C}$.

$\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ ceramic developed in the present study has a low sintering temperature (915°C), a good combination of microwave dielectric properties ($\epsilon_r = 9.9$, $Q_u \times f = 50,600$ GHz), low bulk density ($< 3.5 \text{ g/cm}^3$) and low cost (cheap raw materials). However, the temperature stability of resonant frequency is poor ($\tau_f = -47$ ppm/ $^\circ\text{C}$) which precludes its use as substrate material for practical applications. The value of τ_f can be tuned nearly to zero by adding ceramics with a large positive τ_f value like CaTiO_3 ($\tau_f = +800$ ppm/ $^\circ\text{C}$) [18]. A similar approach was recently used by Huang and Tseng to tailor τ_f of $\text{Ca}_4\text{MgNb}_2\text{TiO}_{12}$ ceramics [22]. The addition of 30 mol% CaTiO_3 to $\text{Ca}_4\text{MgNb}_2\text{TiO}_{12}$ ($\tau_f \sim -32$ ppm/ $^\circ\text{C}$) results in a ceramic composite exhibiting $\epsilon_r \sim 43.88$, $Q_u \times f \sim 20,200$ GHz and $\tau_f \sim -6.9$ ppm/ $^\circ\text{C}$ [23]. In this paper, the microwave dielectric properties and XRD patterns of $(1-x)\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}-x\text{CaTiO}_3$ ($0 \leq x \leq 0.2$) ceramics sintered at

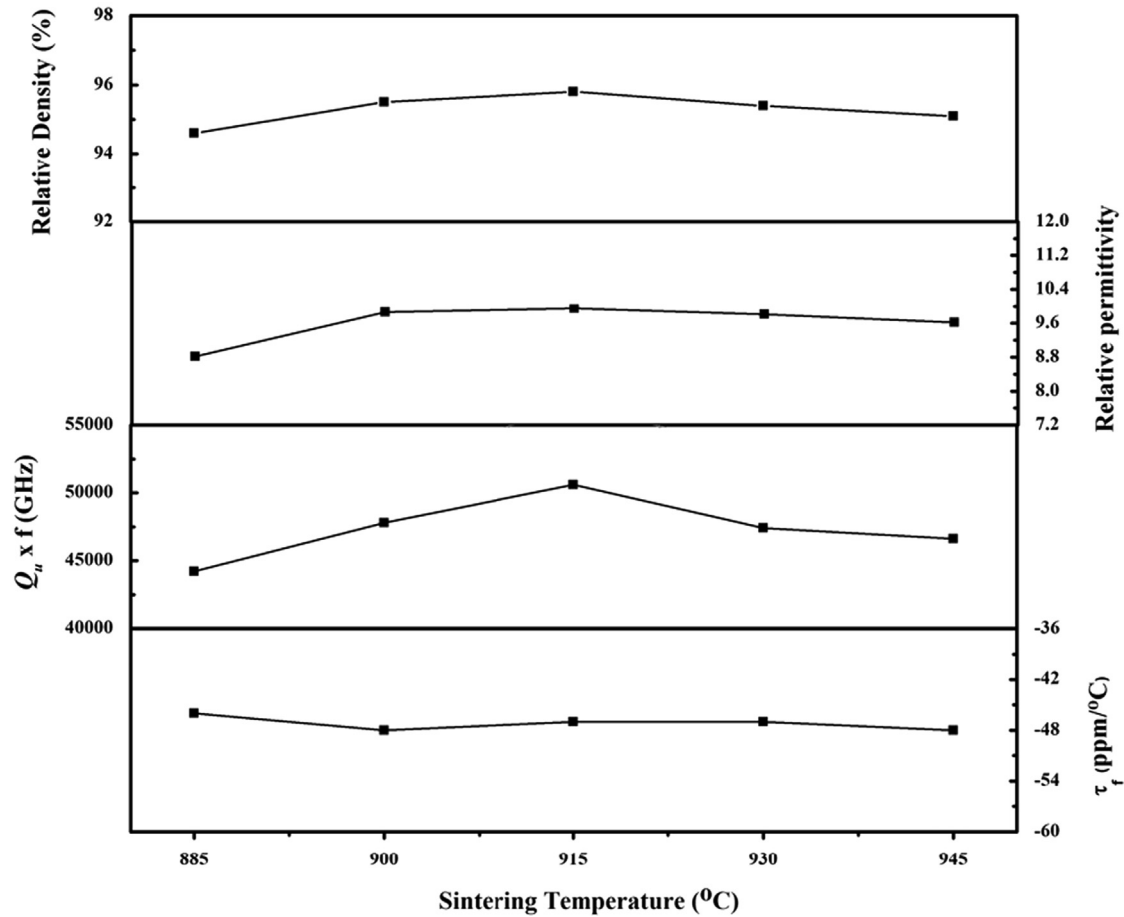


Fig. 2. The relative density, relative permittivity, quality factor, and temperature coefficient of the resonant frequency of $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ ceramic as a function of sintering temperature.

Table 1

Bulk density and microwave dielectric properties of $(1-x)\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}-x\text{CaTiO}_3$ ($0 \leq x \leq 0.2$) ceramics sintered at 930 °C for 4 h.

x value	Bulk density (g/cm^3)	ϵ_r	$Q_u \times f$ (GHz)	τ_f (ppm/°C)
0	3.28	9.8	47,400	−47
0.05	3.25	10.1	45,600	−40
0.1	3.20	10.7	41,900	−28
0.2	3.16	11.5	37,500	2

930 °C for 4 h are shown in Table 1 and Fig. 3. The ϵ_r values increased from 9.8 to 11.5 and the τ_f values increased from −47 to 2 ppm/°C with increasing x values from 0 to 0.6. All the sintered ceramics exhibited high $Q_u \times f$ values. The $0.8\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}-0.2\text{CaTiO}_3$ ceramic sintered at 930 °C exhibits favorable microwave dielectric properties with $\epsilon_r=11.5$, $Q_u \times f=37,500$ GHz, and $\tau_f=2$ ppm/°C. Fig. 4 shows the result from energy-dispersive spectroscopy of second phase in $0.8\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}-0.2\text{CaTiO}_3$ ceramic sintered at 930 °C. Ca and Ti element are detected at a ratio of approximately 1:1, which confirms CaTiO_3 as the secondary phase.

For chemical compatibility experiment, mixtures of ceramic powders with 20 wt% Ag powders were cofired and analyzed to detect interactions between the low-fired samples and

electrodes. The X-ray powder diffraction pattern (XRPD) and the backscattered electron image of $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ cofired with Ag at 915 °C are presented in Fig. 5. Since the XRD pattern does not show the formation of any other phase except for $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ and Ag, and the backscattered electron image of $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}/\text{Ag}$ sample cofired at 915 °C for 2 h reveals no interaction to form new phases after firing, then it is considered that the $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ compound has a chemical compatibility with silver.

4. Conclusions

Novel low firing temperature vanadate garnet $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ ceramic was investigated as promising low-loss dielectric ceramic

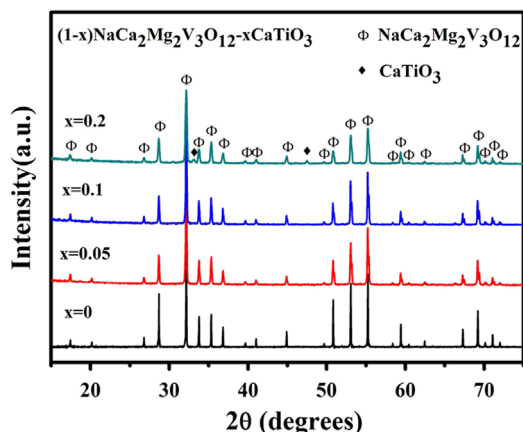


Fig. 3. XRD patterns of $(1-x)\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}-x\text{CaTiO}_3$ ($0 \leq x \leq 0.2$) ceramics sintered at 930 °C for 4 h.

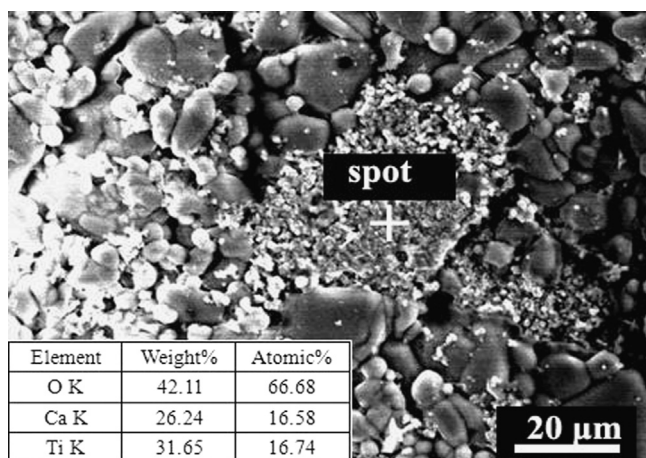


Fig. 4. FE-SEM image of $0.8\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}-0.2\text{CaTiO}_3$ ceramic sintered at 930 °C. Inset shows result of energy-dispersive spectroscopy of second phase in $0.8\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}-0.2\text{CaTiO}_3$.

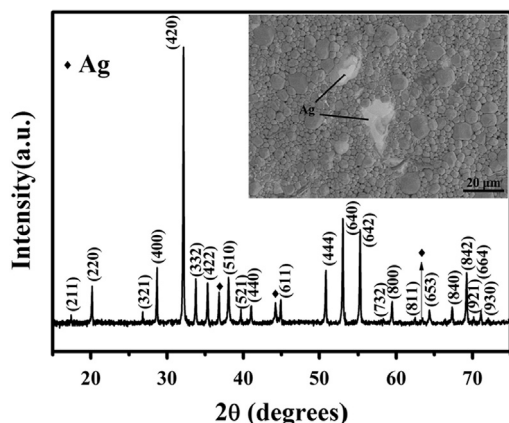


Fig. 5. XRD pattern of a $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ ceramic mixed with 20 wt% Ag sintered at 915 °C for 2 h. Inset shows a backscattered electron image of $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ sample cofired with Ag.

for microwave applications. NCMV ceramic can be densified at a relatively low sintering temperature of 915 °C and exhibited promising microwave dielectric properties of $\epsilon_r=10$, $Q_u \times f=50,600$ GHz, and $\tau_f=-47$ ppm/°C. It was showed that

the microwave properties were improved by adding a small amount of CaTiO_3 into NCMV, and the $0.8\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}-0.2\text{CaTiO}_3$ ceramic sintered at 930 °C for 4 h exhibited improved properties of $\epsilon_r=11.5$, $Q_u \times f=37,500$ GHz, and $\tau_f=2$ ppm/°C. The backscattered electron image and XRD analysis confirmed that the ceramic did not react with silver powders, indicating that $\text{NaCa}_2\text{Mg}_2\text{V}_3\text{O}_{12}$ might be an attractive promising candidate for LTCC application.

Acknowledgments

This work was supported by the Natural Science Foundation of China (Nos. 21261007, 21061004, and 51102058), the Natural Science Foundation of Guangxi (Grant no. 2012GXNSFDA053024), Project of Department of Science and Technology of Guangxi (No.11107006-42) and Guilin (No.20120112-1), and Program to Sponsor Teams for Innovation in the Construction of Talent Highlands in Guangxi Institutions of Higher Learning.

References

- [1] M.T. Sebastian, *Dielectric Materials for Wireless Communications*, Elsevier Publishers, Oxford UK, 2008.
- [2] I.M. Reaney, D. Iddles, Microwave dielectric ceramics for resonators and filters in mobile phone networks, *Journal of the American Ceramic Society* 89 (2006) 2063–2072.
- [3] L. Fang, D.J. Chu, C.C. Li, H.F. Zhou, Z. Yang, Effects of $\text{BaCu}(\text{B}_2\text{O}_5)$ addition on phase transition, sintering temperature, and microwave properties of $\text{Ba}_4\text{LiNb}_3\text{O}_{12}$ ceramics, *Journal of the American Ceramic Society* 94 (2008) 524–528.
- [4] A.K. Axelsson, N.M. Alford, Bismuth titanates candidates for high permittivity LTCC, *Journal of European Ceramic Society* 26 (2006) 1933–1936.
- [5] P.S. Anjana, M.T. Sebastian, Microwave dielectric properties and low-temperature sintering of cerium oxide for LTCC applications, *Journal of the American Ceramic Society* 92 (2009) 96–104.
- [6] H. Ohsato, T. Tsunooka, A. Kan, Y. Ohishi, Y. Miyauchi, Y. Tohdo, T. Okawa, K. Kakimoto, H. Ogawa, Microwave–millimeterwave dielectric materials, *Key Engineering Materials* 269 (2004) 195–198.
- [7] T. Tsunooka, T. Sugiyama, H. Ohsato, K. Kakimoto, M. Andou, Y. Higashida, H. Sugiura, Development of forsterite with high Q and zero temperature coefficient τ_f for millimeterwave dielectric ceramics, *Key Engineering Materials* 269 (2004) 199–202.
- [8] H. Ogawa, A. Kan, S. Ishihara, Y. Higashida, Crystal structure of corundum type $\text{Mg}_4(\text{Nb}_{2-x}\text{Ta}_x)\text{O}_9$ microwave dielectric ceramics with low dielectric loss, *Journal of European Ceramic Society* 23 (2004) 2485–2488.
- [9] M.E. Song, J.S. Kim, M.R. Joong, S. Nahm, Y.S. Kim, J.H. Paik, B.H. Choi, Synthesis and microwave dielectric properties of MgSiO_3 ceramics, *Journal of the American Ceramic Society* 91 (2008) 2747–2750.
- [10] D. Zhou, H. Wang, X. Yao, L.X. Pang, Microwave dielectric properties of low temperature firing $\text{Bi}_2\text{Mo}_2\text{O}_9$ ceramic, *Journal of the American Ceramic Society* 91 (2008) 3419–3422.
- [11] H.F. Zhou, X.L. Chen, L. Fang, D.J. Chu, H. Wang, A new low-loss microwave dielectric ceramic for low temperature cofired ceramic applications, *Journal of Materials Research* 25 (2010) 1235–1238.
- [12] L. Fang, D.J. Chu, H.F. Zhou, X.L. Chen, Z. Yang, Microwave dielectric properties and low temperature sintering behavior of $\text{Li}_2\text{CoTi}_3\text{O}_8$ ceramic, *Journal of Alloys and Compounds* 509 (2011) 1880–1884.
- [13] D.K. Kwon, M.T. Lanagan, T.R. Shrout, Microwave dielectric properties of $\text{BaO}-\text{TeO}_2$ binary compounds, *Materials Letters* 6 (2007) 1827–1831.

- [14] M.R. Joung, J.S. Kim, M.E. Song, S. Nahm, J.H. Paik, B.H. Choi, Formation process and microwave dielectric properties of the $\text{Mg}_2\text{V}_2\text{O}_7$ ceramics, *Journal of the American Ceramic Society* 92 (2009) 1621–1624.
- [15] M.R. Joung, J.S. Kim, M.E. Song, S. Nahm, J.H. Paik, Formation process and microwave dielectric properties of the $\text{R}_2\text{V}_2\text{O}_7$ (R = Ba, Sr and Ca) ceramics, *Journal of the American Ceramic Society* 92 (2009) 3092–3094.
- [16] L. Fang, C.X. Su, H.F. Zhou, Z.H. Wei, H. Zhang, Novel low-firing microwave dielectric ceramic $\text{LiCa}_3\text{MgV}_3\text{O}_{12}$ with low dielectric loss, *Journal of the American Ceramic Society* 96 (2013) 688–690.
- [17] G. Bayer, Vanadates $\text{A}_3\text{B}_2\text{V}_3\text{O}_{12}$ with garnet structure, *Journal of the American Ceramic Society* 48 (1965) 600.
- [18] A. Templeton, X. Wang, S.J. Penn, S.J. Webb, L.F. Cohn, N.M. Alford, Microwave dielectric loss of titanium oxide, *Journal of the American Ceramic Society* 83 (2000) 95–100.
- [19] X.G. Wu, H. Wang, Y.H. Chen, D. Zhou, Synthesis and microwave dielectric properties of $\text{Zn}_3\text{B}_2\text{O}_6$ ceramics for substrate application, *Journal of the American Ceramic Society* 95 (2012) 1793–1795.
- [20] A.J. Bosman, E.E. Havinga, Temperature dependence of dielectric constants of cubic ionic compounds, *Physical Review* 129 (1963) 1593–1600.
- [21] L.J. Liu, H.Q. Fan, L. Fang, X.L. Chen, H. Dammak, M.P. Thi, Effects of Na/K evaporation on electrical properties and intrinsic defects in $\text{Na}_{0.5}\text{K}_{0.5}\text{NbO}_3$ ceramics, *Materials Chemistry and Physics* 117 (2009) 138–141.
- [22] C.L. Huang, Y.W. Tseng, Structure, dielectric properties, and applications of CaTiO_3 -modified $\text{Ca}_4\text{MgNb}_2\text{TiO}_{12}$ ceramics at microwave frequency, *Journal of the American Ceramic Society* 94 (2011) 1824–1828.
- [23] P.V. Bijumon, M.T. Sebastian, P. Mohanan, Experimental investigations and three-dimensional transmission line matrix simulation of $\text{Ca}_{5-x}\text{A}_x\text{B}_2\text{-TiO}_{12}$ (A = Mg, Zn, Ni, and Co; B = Nb and Ta) ceramic resonators, *Japanese Journal of Applied Physics* 98 (2005) 124105.